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July 1, 1998

TO: Commissioner of Patents and Trademarks  
Washington, D.C. 20231  
Application Processing Division's  
Customer Correction Branch

FROM: George O. Saile, Reg. No. 19,572  
20 McIntosh Drive  
Poughkeepsie, N.Y. 12603

SUBJECT: Serial No. 09/086,772 05/29/98  
S.M. JANG  
HARD MASKING METHOD FOR FORMING  
PATTERNEO OXYGEN CONTAINING  
PLASMA ETCHABLE LAYER

REQUEST TO CORRECT FILING RECEIPT

In the copy of the enclosed Filing Receipt,  
the second Applicant was omitted. Please add  
"MING-HSIN HUANG, HSIN-CHU, TAIWAN" to the list of  
Applicants on the Filing Receipt.

Please make the necessary changes to correct  
the error on the Filing Receipt. A copy of the  
filed declaration is enclosed for clarification.  
Please direct any questions to George O. Saile and  
Associates at (914) 452-5863.

Sincerely,  
*George O. Saile*  
George O. Saile  
Reg. No. 19,572

Enclosure

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JUN. 22 1998

PTO-103X  
(Rev. 8-85)

FILING RECEIPT



UNITED STATES DEPARTMENT OF COMMERCE  
Patent and Trademark Office  
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APPLICATION NUMBER	TRADEMARK DATE	GRP ART UNIT	FIL FEE REC'D	ATTORNEY DOCKET NO.	DRWGS	TOT CL	IND CL
09/086,772	05/29/98	1763	\$790.00	TSMC97-306	2	16	2

GEORGE O. SAILE  
20 MCINTOSH DRIVE  
POUGHKEEPSIE NY 12603

Receipt is acknowledged of this nonprovisional Patent Application. It will be considered in its order and you will be notified as to the results of the examination. Be sure to provide the U.S. APPLICATION NUMBER, FILING DATE, NAME OF APPLICANT, and TITLE OF INVENTION when inquiring about this application. Fees transmitted by check or draft are subject to collection. Please verify the accuracy of the data presented on this receipt. If an error is noted on this Filing Receipt, please write to the Application Processing Division's Customer Correction Branch within 10 days of receipt. Please provide a copy of the Filing Receipt with the changes noted thereon.

## Applicant(s)

SYUN-MING JANG, HSIN-CHU, TAIWAN.

## TITLE

HARD MASKING METHOD FOR FORMING PATTERNED OXYGEN CONTAINING PLASMA ETCHABLE LAYER

PRELIMINARY CLASS: 216

## DECLARATION AND POWER OF ATTORNEY FOR PATENT APPLICATION

DOCKET NO. TSMC97-306

As a below named Inventor, I hereby declare that:

My residence, post office address and citizenship are as stated below next to my name;

I believe I am the original, first and sole inventor (if only one name is listed below) or an original, first and joint inventor (if plural names are listed below) of the subject matter which is claimed and for which a patent is sought on the invention entitled

Hard Masking Method for Forming Patterned Oxygen Containing Plasma Etchable Layer

the specification of which (check one)

X is attached hereto.

was filed on \_\_\_\_\_

Application Serial No. \_\_\_\_\_

and was amended on \_\_\_\_\_ (if applicable)

I hereby state that I have reviewed and understand the contents of the above Identified specification including the claims, as amended by any amendment referred to above.

I acknowledge the duty to disclose information which is material to the examination of this application in accordance with Title 37, Code of Federal Regulations, §1.56(a).

I hereby claim foreign priority benefits under Title 35, United States Code §119 of any foreign application(s) for patent or inventor's certificate listed below and have also identified below any foreign application for patent or inventor's certificate having a filing date before that of the application on which priority is claimed:

Prior Foreign Application(s)

Priority Claimed:

(Number)	(Country)	(Day/Month/Year Filed)
(Number)	(Country)	(Day/Month/Year Filed)

I hereby claim the benefit under Title 35, United States Code §120 of any United States application(s) listed below and, insofar as the subject matter of each of the claims of this application is not disclosed in the prior United States application in the manner provided by the first paragraph of Title 35, United States Code, §112, I acknowledge the duty to disclose material information as defined in Title 37, Code of Federal Regulations, §1.56(a) which occurred between the filing date of the prior application and the national or PCT international filing date of this application:

(Application Serial No.) (Filing Date) (Status) (patented, pending, abandoned)

I hereby declare that all statements made herein of my own knowledge are true and that all statements made on information and belief are believed to be true; and further that these statements were made with the knowledge that willful false statements and the like so made are punishable by fine or imprisonment, or both, under Section 1001 of Title 18 of the United States Code and that such willful false statements may jeopardize the validity of the application or any patent issued thereon.

POWER OF ATTORNEY: As a named inventor, I hereby appoint the following attorney(s) and/or agent(s) to prosecute this application and transact all business in the Patent and Trademark Office connected therewith. (list name &amp; registration no.)

GEORGE O. SAILE. (Reg. No. 19,572), STEPHEN B. ACKERMAN (Reg. No. 37,761)

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Full name of sole or first inventor

Syuan-Ming Jang

Date

5/5/98

Inventor's signature

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✓ MING - HSIN HUANG

OCKET NO. TSMC97-306

Full name of second inventor

Date

Meng-Hsueh Huang

5/15/98

Inventor's signature

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